

## LH4002 Wideband Video Buffer

### General Description

The LH4002 is a high speed voltage follower designed to drive video signals from DC up to 200 MHz. At voltage supplies of  $\pm 5V$ , the LH4002 will provide up to 40 mA into  $50\Omega$  at slew rates in excess of  $1000 V/\mu s$ .

The device is intended to fulfill a wide range of high speed applications including video distribution, impedance transformation, and load isolation. It is also suitable for use in current booster applications within an op amp loop. This allows the output current capability of existing op amps to be increased.

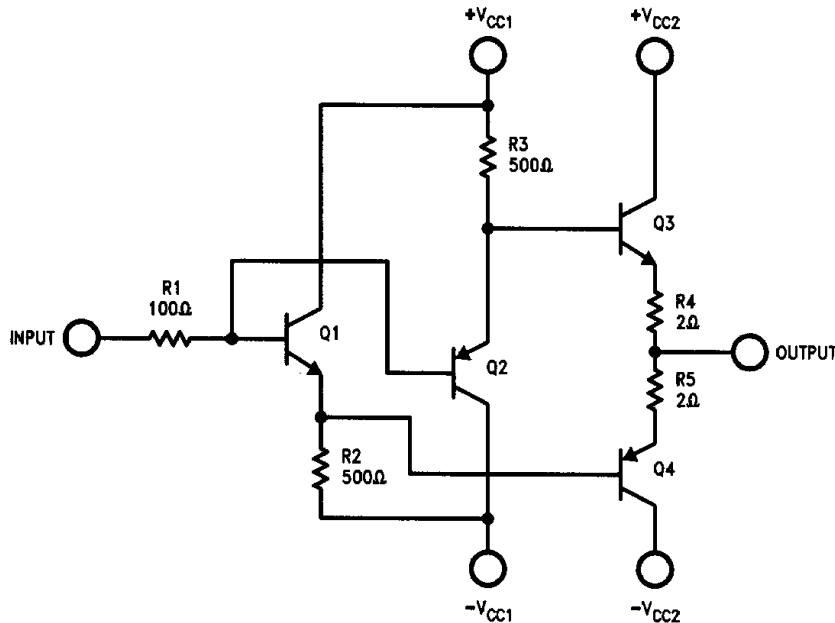
### Features

- DC to 200 MHz Bandwidth with  $V_S = \pm 5V$
- $1250 V/\mu s$  Slew Rate into  $50\Omega$
- 150 MHz Bandwidth with  $V_S = \pm 5V$ ,  $R_L = 50\Omega$  and Voltage Swing =  $2 V_{p-p}$

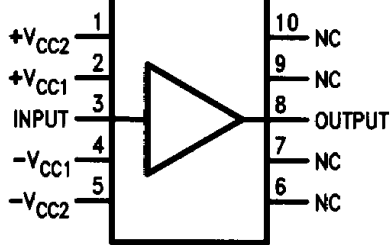
### Applications

- Wideband Buffer Amplifiers
- Wideband Line Driver

### Schematic and Connection Diagrams

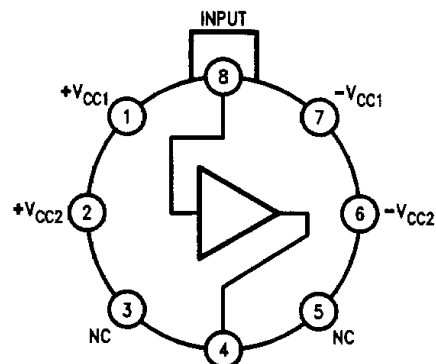


TL/K/8686-15

**Dual-In-Line Package**

**Top View**

Order Number LH4002CN  
See NS Package Number N10A

TL/K/8686-2

**Metal Can Package**

**Top View**

Order Number LH4002CH or LH4002H  
See NS Package Number H08D

TL/K/8686-3

### Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

|                                      |   |
|--------------------------------------|---|
| Supply Voltage, $V_S$                | $\pm 6V$                                    |
| Input Voltage Range, $V_{IN}$        | $\pm V_S$                                   |
| Continuous Output Current, $I_O$     | $\pm 60\text{ mA}$                          |
| Storage Temperature Range, $T_{STG}$ | $-65^\circ\text{C}$ to $+150^\circ\text{C}$ |

Operating Temperature Range,  $T_A$

|         |   |
|---------|---|
| LH4002  | $-55^\circ\text{C}$ to $+125^\circ\text{C}$ |
| LH4002C | $-25^\circ\text{C}$ to $+85^\circ\text{C}$  |

Maximum Junction Temperature,  $T_J$  150°C

Lead Temperature (Soldering, 10 sec) 300°C

ESD rating is to be determined.

### DC Electrical Characteristics $V_{CC} = \pm 5V, T_{min} \leq T_A \leq T_{max}$ unless otherwise stated.

| Symbol    | Parameter            | Conditions   | Min       | Typ       | Max | Units         |
|-----------|----------------------|--|-----------|-----------|-----|---------------|
| $V_{OS}$  | Input Offset Voltage | $T_A = T_J = 25^\circ\text{C}$<br>$R_S = 150\Omega, R_L = 50\Omega$                          |           | 20        | 50  | mV            |
| $I_B$     | Input Bias Current   | $R_S = 1\text{ k}\Omega, R_L = 50\Omega$   |           | 100       | 200 | $\mu\text{A}$ |
| $A_V$     | DC Voltage Gain      | $R_S = 10\text{ k}\Omega, R_L = 1.0\text{ k}\Omega, V_{IN} = \pm 2V$                         | 0.95      | 0.97      |     | V/V           |
| $V_O$     | Output Voltage Swing | $R_S = 150\Omega, V_{IN} = \pm 2.5V, R_L = 1\text{ k}\Omega$                                 | $\pm 2.2$ | $\pm 2.4$ |     | V             |
|           |                      | $T_A = 25^\circ\text{C}, R_L = 50\Omega$   | $\pm 2.0$ | $\pm 2.2$ |     | V             |
| $I_S$     | Supply Current       | $R_S = 10\text{ k}\Omega, V_{IN} = 0V, R_L = 1\text{ k}\Omega, T_A = T_J = 25^\circ\text{C}$ |           | 20        | 35  | mA            |
| $R_{OUT}$ | Output Resistance    | $R_S = 10\text{ k}\Omega, R_L = 50\Omega$  |           | 6         | 10  | $\Omega$      |
| $R_{IN}$  | Input Resistance     | $R_S = 10\text{ k}\Omega, R_L = 50\Omega$  | 10        | 18        |     | k $\Omega$    |

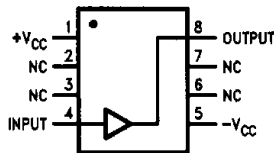
### AC Electrical Characteristics $V_{CC} = \pm 5V, T_A = 25^\circ\text{C}$ .

| Symbol    | Parameter           | Conditions  | Min  | Typ  | Max | Units            |
|-----------|---------------------|---|------|------|-----|------------------|
| $S_R$     | Slew Rate           | $R_L = 50\Omega, R_S = 50\Omega$<br>$V_{IN} = \pm 2V$ | 1000 | 1250 |     | V/ $\mu\text{s}$ |
| $f_{3dB}$ | Bandwidth, -3 dB    | $R_S = 50\Omega, R_L = 50\Omega, V_{OUT} = 4V_{P-P}$  |      | 125  |     | MHz              |
|           |                     | $R_S = 50\Omega, R_L = 50\Omega, V_{OUT} = 2V_{P-P}$  | 100  | 150  |     | MHz              |
|           |                     | (Note 2) $V_{OUT} = 100\text{ mV}_{P-P}$              |      | 200  |     | MHz              |
|           | Phase Non-Linearity | $BW = 1.0\text{--}20\text{ MHz}$                      |      | 2.0  |     | degrees          |
| $t_r$     | Rise Time           | $\Delta V_{IN} = 0.5V$                                |      | 3    |     | ns               |
| $t_d$     | Propagation Delay   | $\Delta V_{IN} = 0.5V$                                |      | 1.2  |     | ns               |
| THD       | Harmonic Distortion | $f = 1\text{ kHz}$                                    |      | 0.1  |     | %                |

Note 1: Under normal operating conditions  $+V_{CC1}$  and  $+V_{CC2}$  should be connected together, and  $-V_{CC1}$  and  $-V_{CC2}$  should be connected together.

Note 2: Guaranteed by design. This parameter is sample tested.

### Connection Diagrams (Continued)

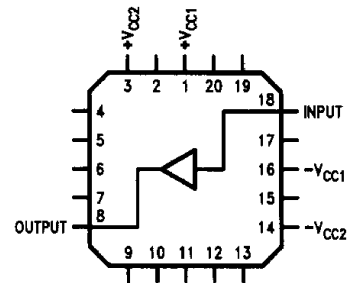


Top View

Order Number LH4002CN-8  
See NS Package Number N08E

Note:  $+V_{CC1}$  and  $+V_{CC2}$  pins and  $-V_{CC1}$  and  $-V_{CC2}$  pins are internally connected.

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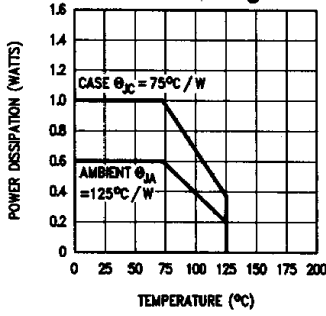
Top View

Order Number LH4002E  
See NS Package Number E20A

TL/K/6686-17

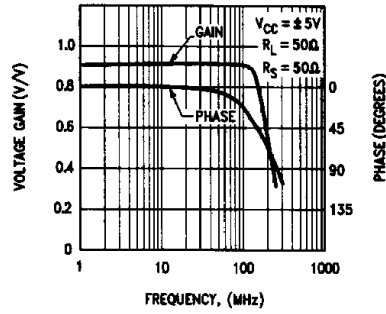
# Typical Performance Characteristics

**Maximum Power Dissipation  
Metal Can Package**



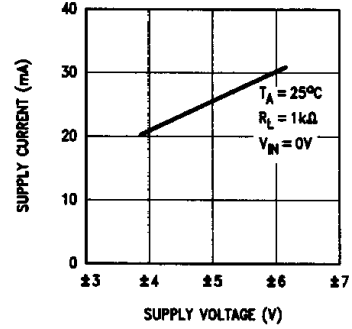
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**Frequency Response**



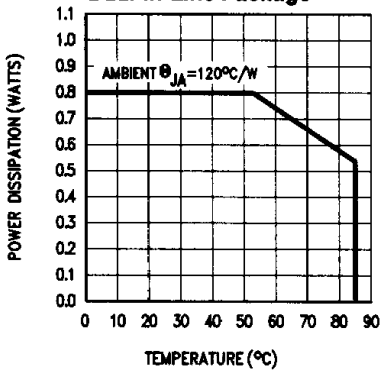
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**Supply Current**



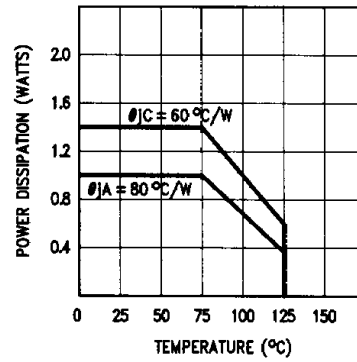
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**Maximum Power Dissipation  
Dual-In-Line Package**



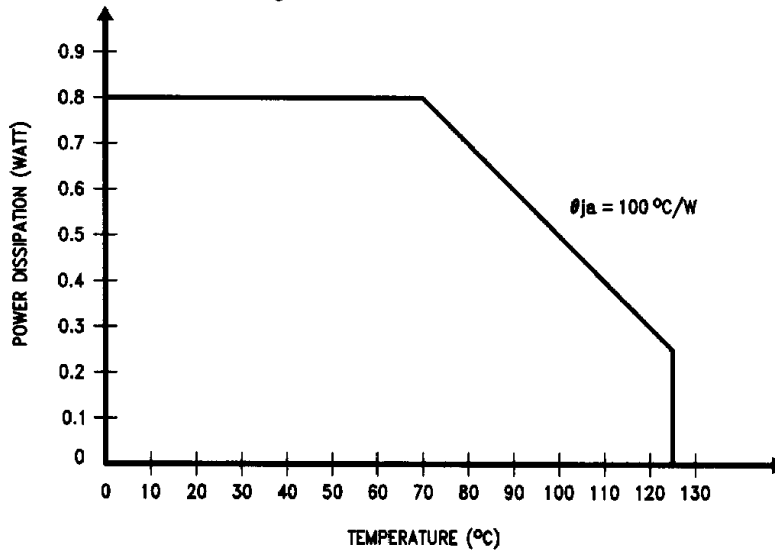
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**Maximum Power Dissipation  
E20A Package**



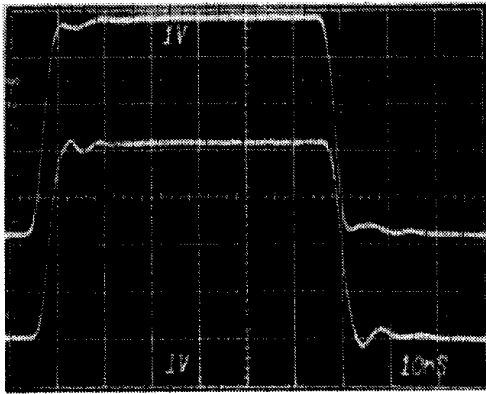
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**Maximum Power Dissipation  
For N08E Package**



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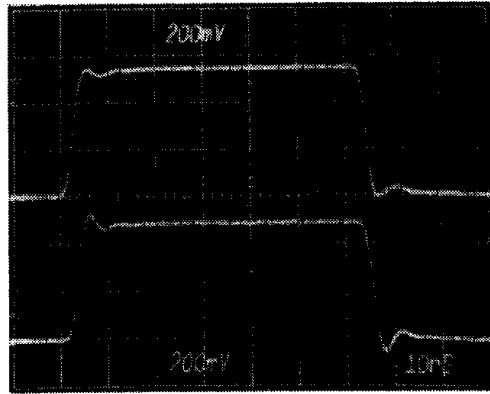
## Pulse Response



TOP TRACE  
= INPUT  
BOTTOM TRACE  
= OUTPUT

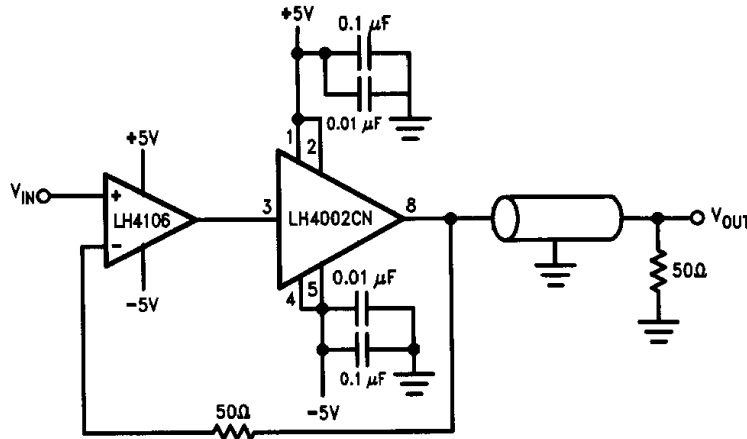
$V_S = \pm 5V$   
 $R_L = 50\Omega$

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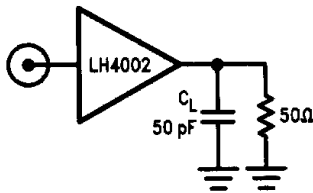
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## Typical Applications



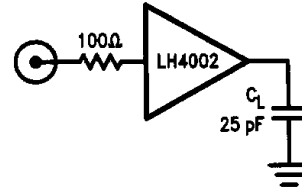
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FIGURE 1. Wideband Unity Gain Amplifier Using LH4002CN



TL/K/8686-9

FIGURE 2. Compensation for Capacitive Loads



TL/K/8686-10

FIGURE 3. Compensation for Capacitive Loads

## Applications Information

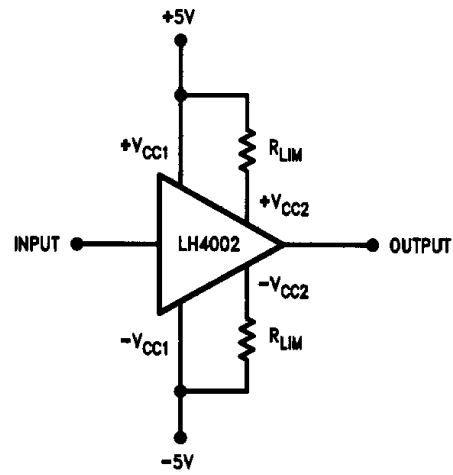
The high speed performance of the LH4002 can only be realized by taking certain precautions in circuit layout and power supply decoupling. Low inductance ceramic chip or disc power supply decoupling capacitors of 0.01  $\mu F$  in parallel with 0.1  $\mu F$  should be connected with the shortest practical lead length between device supply leads and a ground plane. Failure to follow these rules can result in oscillations. When driving a capacitive load such as inputs to flash converters, the circuits in Figure 2 and 3 can be used to minimize the amount of overshoot and ringing at the outputs. Figure 2 indicates that a 50 $\Omega$  should be placed in parallel with the load and Figure 3 recommends that a 100 $\Omega$  resistor be placed in series with the input to the LH4002.

## Short Circuit Protection

In order to optimize transient response and output swing, output current limits have been omitted from the LH4002. Short circuit protection may be added by inserting appropriate value resistors between  $+V_{CC1}$  and  $+V_{CC2}$  pins and between  $-V_{CC1}$  and  $-V_{CC2}$  pins as illustrated in Figure 4. Resistor values may be predicted by:

$$R_{LIM} = \frac{+V_{CC1}}{I_{SC}} = \frac{-V_{CC1}}{I_{SC}}$$

where  $I_{SC} \leq 100 \text{ mA}$ . The inclusion of 50 $\Omega$  limiting resistors in the collectors of the output transistors limits the short circuit current to approximately 100 mA without reducing the output voltage swing.

**Short Circuit Protection** (Continued)

TL/K/8886-20

**FIGURE 4. LH4002 Using Resistor Current Limiting**

This datasheet has been downloaded from:

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Datasheets for electronic components.

# National Semiconductor was acquired by Texas Instruments.

[http://www.ti.com/corp/docs/investor\\_relations/pr\\_09\\_23\\_2011\\_national\\_semiconductor.html](http://www.ti.com/corp/docs/investor_relations/pr_09_23_2011_national_semiconductor.html)

This file is the datasheet for the following electronic components:

LH4002CH - <http://www.ti.com/product/lh4002ch?HQS=TI-null-null-dscatalog-df-pf-null-wwe>

LH4002CN - <http://www.ti.com/product/lh4002cn?HQS=TI-null-null-dscatalog-df-pf-null-wwe>

LH4002H - <http://www.ti.com/product/lh4002h?HQS=TI-null-null-dscatalog-df-pf-null-wwe>